

1、General Description

The 74LVC2G74 is a single positive-edge triggered D-type flip-flop with individual data (D) inputs, clock (CP) inputs, set ($\overline{SD}$) and reset ($\overline{RD}$) inputs, and complementary Q and $\overline{Q}$ outputs.

The set and reset are asynchronous active LOW inputs and operate independently of the clock input. Information on the data input is transferred to the Q output on the LOW-to-HIGH transition of the clock pulse. The D inputs must be stable, one set-up time prior to the LOW-to-HIGH clock transition for predictable operation.

Features:

- Wide supply voltage range from 1.65V to 5.5V
- 5 V tolerant outputs for interfacing with 5 V logic
- $\pm 24\text{mA}$ output drive ($V_{CC}=3.0\text{V}$)
- CMOS low power consumption
- Latch-up performance exceeds 250mA
- Specified from -40°C to $+125^{\circ}\text{C}$
- Packaging information: TSSOP8/VSSOP8

2、Block Diagram And Pin Description

2.1、Block Diagram

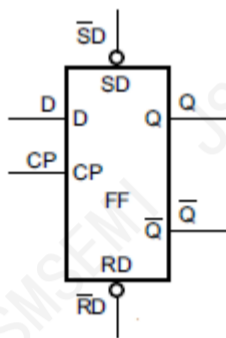


Figure 1. Logic symbol

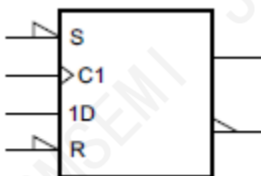


Figure 2. IEC logic symbol

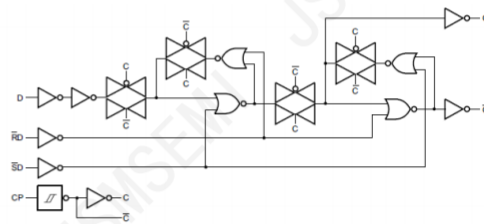
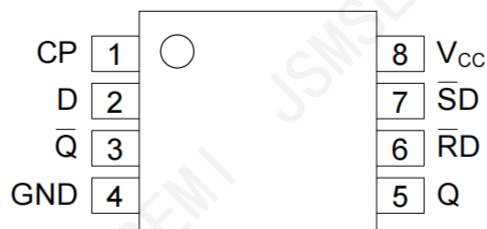


Figure 3. Logic diagram

2.2、Pin Configurations



2.3、Pin Description

Pin No.	Pin Name	Description
1	CP	clock input (LOW-to-HIGH, edge-triggered)
2	D	data input
3	$\bar{Q}$	complement output
4	GND	ground (0V)
5	Q	true output
6	$\bar{RD}$	asynchronous reset-direct input (active LOW)
7	$\bar{SD}$	asynchronous set-direct input (active LOW)
8	V _{CC}	supply voltage

2.4、Function Table

Function table for asynchronous operation

Input				Output	
$\bar{SD}$	$\bar{RD}$	CP	D	Q	$\bar{Q}$
L	H	X	X	H	L
H	L	X	X	L	H
L	L	X	X	H	H

Note: H=HIGH voltage level; L=LOW voltage level; X=don't care.

Function table for synchronous operation

Input				Output	
$\bar{SD}$	$\bar{RD}$	CP	D	Q _{n+1}	$\bar{Q}_{n+1}$
H	H	↑	L	L	H
H	H	↑	H	H	L

Note: H=HIGH voltage level; L=LOW voltage level; ↑=LOW-to-HIGH CP transition;

Q_{n+1}=state after the next LOW-to-HIGH CP transition.

3、Electrical Parameter

3.1、Absolute Maximum Ratings

(Voltages are referenced to GND(ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Max.	Unit
supply voltage	V_{CC}	-	-0.5	+6.5	V
input clamping current	I_{IK}	$V_I < 0V$	-50	-	mA
input voltage	V_I	-	-0.5	+6.5	V
output clamping current	I_{OK}	$V_O > V_{CC}$ or $V_O < 0V$	-	± 50	mA
output voltage	V_O	Active mode	-0.5	$V_{CC}+0.5$	V
		Power-down mode; $V_{CC}=0V$	-0.5	+6.5	V
output current	I_O	$V_O=0V$ to V_{CC}	-	± 50	mA
supply current	I_{CC}	-	-	100	mA
ground current	I_{GND}	-	-100	-	mA
total power dissipation	P_{tot}	-	-	300	mW
storage temperature	T_{stg}	-	-65	+150	°C
Soldering temperature	T_L	10s	260		°C

3.2、Recommended Operating Conditions

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
supply voltage	V_{CC}	-	1.65	-	5.5	V
input voltage	V_I	-	0	-	5.5	V
output voltage	V_O	Active mode	0	-	V_{CC}	V
		Power-down mode; $V_{CC}=0V$	0	-	5.5	V
ambient temperature	T_{amb}	-	-40	-	+125	°C

3.3. Electrical Characteristics

3.3.1. DC Characteristics 1

($T_{amb} = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
HIGH-level input voltage	V_{IH}	$V_{CC}=1.65\text{V to }1.95\text{V}$		$0.65 \times V_{CC}$	-	-	V
		$V_{CC}=2.3\text{V to }2.7\text{V}$		1.7	-	-	V
		$V_{CC}=2.7\text{V to }3.6\text{V}$		2.0	-	-	V
		$V_{CC}=4.5\text{V to }5.5\text{V}$		$0.7 \times V_{CC}$	-	-	V
LOW-level input voltage	V_{IL}	$V_{CC}=1.65\text{V to }1.95\text{V}$		-	-	$0.35 \times V_{CC}$	V
		$V_{CC}=2.3\text{V to }2.7\text{V}$		-	-	0.7	V
		$V_{CC}=2.7\text{V to }3.6\text{V}$		-	-	0.8	V
		$V_{CC}=4.5\text{V to }5.5\text{V}$		-	-	$0.3 \times V_{CC}$	V
HIGH-level output voltage	V_{OH}	$V_I = V_{IH} \text{ or } V_{IL}$	$I_O = -100\mu\text{A}; V_{CC}=1.65\text{V to }5.5\text{V}$	$V_{CC}-0.1$	-	-	V
			$I_O = -4\text{mA}; V_{CC}=1.65\text{V}$	1.2	1.54	-	V
			$I_O = -8\text{mA}; V_{CC}=2.3\text{V}$	1.9	2.15	-	V
			$I_O = -12\text{mA}; V_{CC}=2.7\text{V}$	2.2	2.50	-	V
			$I_O = -24\text{mA}; V_{CC}=3.0\text{V}$	2.3	2.62	-	V
			$I_O = -32\text{mA}; V_{CC}=4.5\text{V}$	3.8	4.11	-	V
LOW-level output voltage	V_{OL}	$V_I = V_{IH} \text{ or } V_{IL}$	$I_O = 100\mu\text{A}; V_{CC}=1.65\text{V to }5.5\text{V}$	-	-	0.10	V
			$I_O = 4\text{mA}; V_{CC}=1.65\text{V}$	-	0.07	0.45	V
			$I_O = 8\text{mA}; V_{CC}=2.3\text{V}$	-	0.12	0.30	V
			$I_O = 12\text{mA}; V_{CC}=2.7\text{V}$	-	0.17	0.40	V
			$I_O = 24\text{mA}; V_{CC}=3.0\text{V}$	-	0.33	0.55	V
			$I_O = 32\text{mA}; V_{CC}=4.5\text{V}$	-	0.39	0.55	V
input leakage current	I_I	$V_I = 5.5\text{V or GND}; V_{CC}=0\text{V to }5.5\text{V}$		-	-	± 1	μA
power-off leakage current	I_{OFF}	$V_I \text{ or } V_O = 5.5\text{V}; V_{CC}=0\text{V}$		-	-	± 2	μA
supply current	I_{CC}	$V_I = 5.5\text{V or GND}; I_O = 0\text{A}; V_{CC}=1.65\text{V to }5.5\text{V}$		-	-	4	μA
additional supply current	ΔI_{CC}	per pin; $V_I = V_{CC}-0.6\text{V}; I_O = 0\text{A}; V_{CC}=2.3\text{V to }5.5\text{V}$		-	-	500	μA
input capacitance	C_I	-		-	4.0	-	pF

Note: All typical values are measured at $T_{amb} = 25^{\circ}\text{C}$.

3.3.2、DC Characteristics 2

($T_{amb} = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
HIGH-level input voltage	V_{IH}	$V_{CC}=1.65\text{V}$ to 1.95V		$0.65 \times V_{CC}$	-	-	V
		$V_{CC}=2.3\text{V}$ to 2.7V		1.7	-	-	V
		$V_{CC}=2.7\text{V}$ to 3.6V		2.0	-	-	V
		$V_{CC}=4.5\text{V}$ to 5.5V		$0.7 \times V_{CC}$	-	-	V
LOW-level input voltage	V_{IL}	$V_{CC}=1.65\text{V}$ to 1.95V		-	-	$0.35 \times V_{CC}$	V
		$V_{CC}=2.3\text{V}$ to 2.7V		-	-	0.7	V
		$V_{CC}=2.7\text{V}$ to 3.6V		-	-	0.8	V
		$V_{CC}=4.5\text{V}$ to 5.5V		-	-	$0.3 \times V_{CC}$	V
HIGH-level output voltage	V_{OH}	$V_I = V_{IH}$ or V_{IL}	$I_O = -100\mu\text{A}; V_{CC}=1.65\text{V}$ to 5.5V	$V_{CC} - 0.1$	-	-	V
			$I_O = -4\text{mA}; V_{CC}=1.65\text{V}$	0.95	-	-	V
			$I_O = -8\text{mA}; V_{CC}=2.3\text{V}$	1.7	-	-	V
			$I_O = -12\text{mA}; V_{CC}=2.7\text{V}$	1.9	-	-	V
			$I_O = -24\text{mA}; V_{CC}=3.0\text{V}$	2.0	-	-	V
			$I_O = -32\text{mA}; V_{CC}=4.5\text{V}$	3.4	-	-	V
LOW-level output voltage	V_{OL}	$V_I = V_{IH}$ or V_{IL}	$I_O = 100\mu\text{A}; V_{CC}=1.65\text{V}$ to 5.5V	-	-	0.10	V
			$I_O = 4\text{mA}; V_{CC}=1.65\text{V}$	-	-	0.70	V
			$I_O = 8\text{mA}; V_{CC}=2.3\text{V}$	-	-	0.45	V
			$I_O = 12\text{mA}; V_{CC}=2.7\text{V}$	-	-	0.60	V
			$I_O = 24\text{mA}; V_{CC}=3.0\text{V}$	-	-	0.80	V
			$I_O = 32\text{mA}; V_{CC}=4.5\text{V}$	-	-	0.80	V
input leakage current	I_I	$V_I = 5.5\text{V}$ or GND; $V_{CC} = 0\text{V}$ to 5.5V		-	-	± 1	μA
power-off leakage current	I_{OFF}	V_I or $V_O = 5.5\text{V}; V_{CC} = 0\text{V}$		-	-	± 2	μA
supply current	I_{CC}	$V_I = 5.5\text{V}$ or GND; $I_O = 0\text{A}; V_{CC} = 1.65\text{V}$ to 5.5V		-	-	4	μA
additional supply current	ΔI_{CC}	per pin; $V_I = V_{CC} - 0.6\text{V}; I_O = 0\text{A}; V_{CC} = 2.3\text{V}$ to 5.5V		-	-	500	μA

3.3.3、AC Characteristics 1

($T_{amb} = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Typ. ^[1]	Max.	Unit
propagation delay	t _{PHL}	CP to Q, $\bar{Q}$; see Figure 5	V _{CC} =1.65V to 1.95V	-	12.5	18.8	ns
			V _{CC} =2.3V to 2.7V	-	10.5	15.8	ns
			V _{CC} =2.7V	-	10	15	ns
			V _{CC} =3.0V to 3.6V	-	9.5	14.3	ns
			V _{CC} =4.5V to 5.5V	-	9	13.5	ns
		$\bar{SD}$ to Q, $\bar{Q}$; see Figure 6	V _{CC} =1.65V to 1.95V	-	12.5	18.8	ns
			V _{CC} =2.3V to 2.7V	-	10.5	15.8	ns
			V _{CC} =2.7V	-	10	15	ns
			V _{CC} =3.0V to 3.6V	-	9.5	14.3	ns
			V _{CC} =4.5V to 5.5V	-	9	13.5	ns
		$\bar{RD}$ to Q, $\bar{Q}$; see Figure 6	V _{CC} =1.65V to 1.95V	-	12.5	18.8	ns
			V _{CC} =2.3V to 2.7V	-	10.5	15.8	ns
			V _{CC} =2.7V	-	10	15	ns
			V _{CC} =3.0V to 3.6V	-	9.5	14.3	ns
			V _{CC} =4.5V to 5.5V	-	9	13.5	ns
propagation delay	t _{PLH}	CP to Q, $\bar{Q}$; see Figure 5	V _{CC} =1.65V to 1.95V	-	14	21	ns
			V _{CC} =2.3V to 2.7V	-	10	15	ns
			V _{CC} =2.7V	-	9.5	14.3	ns
			V _{CC} =3.0V to 3.6V	-	8.5	12.8	ns
			V _{CC} =4.5V to 5.5V	-	7.5	11.3	ns
		$\bar{SD}$ to Q, $\bar{Q}$; see Figure 6	V _{CC} =1.65V to 1.95V	-	14	21	ns
			V _{CC} =2.3V to 2.7V	-	10	15	ns
			V _{CC} =2.7V	-	9.5	14.3	ns
			V _{CC} =3.0V to 3.6V	-	8.5	12.8	ns
			V _{CC} =4.5V to 5.5V	-	7.5	11.3	ns
		$\bar{RD}$ to Q, $\bar{Q}$; see Figure 6	V _{CC} =1.65V to 1.95V	-	14	21	ns
			V _{CC} =2.3V to 2.7V	-	10	15	ns
			V _{CC} =2.7V	-	9.5	14.3	ns
			V _{CC} =3.0V to 3.6V	-	8.5	12.8	ns
			V _{CC} =4.5V to 5.5V	-	7.5	11.3	ns
pulse width	t _w	CP HIGH or LOW; see Figure 5	V _{CC} =1.65V to 1.95V	6.2	-	-	ns
			V _{CC} =2.3V to 2.7V	2.7	-	-	ns
			V _{CC} =2.7V	2.7	-	-	ns
			V _{CC} =3.0V to 3.6V	2.7	1.3	-	ns
			V _{CC} =4.5V to 5.5V	2.0	-	-	ns
		$\bar{SD}$ and $\bar{RD}$ LOW; see Figure 6	V _{CC} =1.65V to 1.95V	6.2	-	-	ns
			V _{CC} =2.3V to 2.7V	2.7	-	-	ns
			V _{CC} =2.7V	2.7	-	-	ns
			V _{CC} =3.0V to 3.6V	2.7	1.6	-	ns
			V _{CC} =4.5V to 5.5V	2.0	-	-	ns
recovery time	t _{rec}	$\bar{SD}$ or $\bar{RD}$; see Figure 6	V _{CC} =1.65V to 1.95V	1.9	-	-	ns
			V _{CC} =2.3V to 2.7V	1.4	-	-	ns

			$V_{CC}=2.7V$	1.3	-	-	ns
			$V_{CC}=3.0V$ to $3.6V$	+1.2	-3.0	-	ns
			$V_{CC}=4.5V$ to $5.5V$	1.0	-	-	ns
			$V_{CC}=1.65V$ to $1.95V$	2.9	-	-	ns
			$V_{CC}=2.3V$ to $2.7V$	1.7	-	-	ns
set-up time	t_{su}	D to CP; see Figure 5	$V_{CC}=2.7V$	1.7	-	-	ns
			$V_{CC}=3.0V$ to $3.6V$	1.3	0.5	-	ns
			$V_{CC}=4.5V$ to $5.5V$	1.1	-	-	ns
			$V_{CC}=1.65V$ to $1.95V$	1.5	-	-	ns
			$V_{CC}=2.3V$ to $2.7V$	1.0	-	-	ns
hold time	t_h	D to CP; see Figure 5	$V_{CC}=2.7V$	1.0	-	-	ns
			$V_{CC}=3.0V$ to $3.6V$	1.0	0.6	-	ns
			$V_{CC}=4.5V$ to $5.5V$	1.0	-	-	ns
			$V_{CC}=1.65V$ to $1.95V$	80	-	-	MHz
			$V_{CC}=2.3V$ to $2.7V$	175	-	-	MHz
maximum frequency	f_{max}	CP; see Figure 5	$V_{CC}=2.7V$	175	-	-	MHz
			$V_{CC}=3.0V$ to $3.6V$	175	280	-	MHz
			$V_{CC}=4.5V$ to $5.5V$	200	-	-	MHz
			$V_{CC}=1.65V$ to $1.95V$	80	-	-	MHz
			$V_{CC}=2.3V$ to $2.7V$	175	-	-	MHz
Power dissipation capacitance	C_{PD}	$V_{CC}=3.3V$; $V_I=GND$ to V_{CC}		-	15	-	pF

Note:

[1] Typical values are measured at $T_{amb}=25^{\circ}C$ and $V_{CC}=1.8V, 2.5V, 2.7V, 3.3V$ and $5.0V$ respectively.

3.3.4、AC Characteristics 2

($T_{amb}=-40^{\circ}C$ to $+125^{\circ}C$, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
propagation delay	t_{PHL}	CP to Q, $\bar{Q}$; see Figure 5	$V_{CC}=1.65V$ to $1.95V$	-	-	20.8 ns
			$V_{CC}=2.3V$ to $2.7V$	-	-	17.8 ns
			$V_{CC}=2.7V$	-	-	17 ns
			$V_{CC}=3.0V$ to $3.6V$	-	-	16.3 ns
			$V_{CC}=4.5V$ to $5.5V$	-	-	15.5 ns
		$\bar{SD}$ to Q, $\bar{Q}$; see Figure 6	$V_{CC}=1.65V$ to $1.95V$	-	-	20.8 ns
			$V_{CC}=2.3V$ to $2.7V$	-	-	17.8 ns
			$V_{CC}=2.7V$	-	-	17 ns
			$V_{CC}=3.0V$ to $3.6V$	-	-	16.3 ns
			$V_{CC}=4.5V$ to $5.5V$	-	-	15.5 ns
		$\bar{RD}$ to Q, $\bar{Q}$; see Figure 6	$V_{CC}=1.65V$ to $1.95V$	-	-	20.8 ns
			$V_{CC}=2.3V$ to $2.7V$	-	-	17.8 ns
			$V_{CC}=2.7V$	-	-	17 ns
			$V_{CC}=3.0V$ to $3.6V$	-	-	16.3 ns
			$V_{CC}=4.5V$ to $5.5V$	-	-	15.5 ns
propagation delay	t_{PLH}	CP to Q, $\bar{Q}$; see Figure 5	$V_{CC}=1.65V$ to $1.95V$	-	-	23 ns
			$V_{CC}=2.3V$ to $2.7V$	-	-	17 ns
			$V_{CC}=2.7V$	-	-	16.3 ns

			$V_{CC}=3.0V$ to $3.6V$	-	-	14.8	ns
			$V_{CC}=4.5V$ to $5.5V$	-	-	13.3	ns
		$\bar{S}D$ to Q , $\bar{Q}$; see Figure 6	$V_{CC}=1.65V$ to $1.95V$	-	-	23	ns
			$V_{CC}=2.3V$ to $2.7V$	-	-	17	ns
			$V_{CC}=2.7V$	-	-	16.3	ns
			$V_{CC}=3.0V$ to $3.6V$	-	-	14.8	ns
			$V_{CC}=4.5V$ to $5.5V$	-	-	13.3	ns
			$V_{CC}=1.65V$ to $1.95V$	-	-	23	ns
		$\bar{R}D$ to Q , $\bar{Q}$; see Figure 6	$V_{CC}=2.3V$ to $2.7V$	-	-	17	ns
			$V_{CC}=2.7V$	-	-	16.3	ns
			$V_{CC}=3.0V$ to $3.6V$	-	-	14.8	ns
			$V_{CC}=4.5V$ to $5.5V$	-	-	13.3	ns
			$V_{CC}=1.65V$ to $1.95V$	6.2	-	-	ns
			$V_{CC}=2.3V$ to $2.7V$	2.7	-	-	ns
			$V_{CC}=2.7V$	2.7	-	-	ns
pulse width	t_W	CP HIGH or LOW; see Figure 5	$V_{CC}=3.0V$ to $3.6V$	2.7	-	-	ns
			$V_{CC}=4.5V$ to $5.5V$	2.0	-	-	ns
			$V_{CC}=1.65V$ to $1.95V$	6.2	-	-	ns
			$V_{CC}=2.3V$ to $2.7V$	2.7	-	-	ns
			$V_{CC}=2.7V$	2.7	-	-	ns
		$\bar{S}D$ and $\bar{R}D$ LOW; see Figure 6	$V_{CC}=3.0V$ to $3.6V$	2.7	-	-	ns
			$V_{CC}=4.5V$ to $5.5V$	2.0	-	-	ns
			$V_{CC}=1.65V$ to $1.95V$	1.9	-	-	ns
			$V_{CC}=2.3V$ to $2.7V$	1.4	-	-	ns
			$V_{CC}=2.7V$	1.3	-	-	ns
recovery time	t_{rec}	$\bar{S}D$ or $\bar{R}D$; see Figure 6	$V_{CC}=3.0V$ to $3.6V$	+1.2	-	-	ns
			$V_{CC}=4.5V$ to $5.5V$	1.0	-	-	ns
			$V_{CC}=1.65V$ to $1.95V$	2.9	-	-	ns
			$V_{CC}=2.3V$ to $2.7V$	1.7	-	-	ns
			$V_{CC}=2.7V$	1.7	-	-	ns
set-up time	t_{su}	D to CP; see Figure 5	$V_{CC}=3.0V$ to $3.6V$	1.3	-	-	ns
			$V_{CC}=4.5V$ to $5.5V$	1.1	-	-	ns
			$V_{CC}=1.65V$ to $1.95V$	1.5	-	-	ns
			$V_{CC}=2.3V$ to $2.7V$	1.0	-	-	ns
			$V_{CC}=2.7V$	1.0	-	-	ns
hold time	t_h	D to CP; see Figure 5	$V_{CC}=3.0V$ to $3.6V$	1.0	-	-	ns
			$V_{CC}=4.5V$ to $5.5V$	1.0	-	-	ns
			$V_{CC}=1.65V$ to $1.95V$	80	-	-	MHz
			$V_{CC}=2.3V$ to $2.7V$	175	-	-	MHz
			$V_{CC}=2.7V$	175	-	-	MHz
maximum frequency	f_{max}	CP; see Figure 5	$V_{CC}=3.0V$ to $3.6V$	175	-	-	MHz
			$V_{CC}=4.5V$ to $5.5V$	200	-	-	MHz

4、Testing Circuit

4.1、AC Testing Circuit

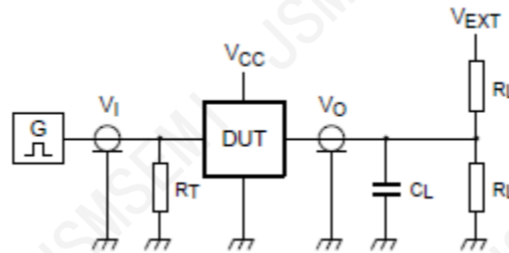


Figure 4. Test circuit for measuring switching times

Definitions for test circuit:

R_L =Load resistance.

C_L =Load capacitance including jig and probe capacitance.

R_T =Termination resistance; should be equal to the output impedance Z_o of the pulse generator.

V_{EXT} =External voltage for measuring switching times.

4.2、AC Testing Waveforms

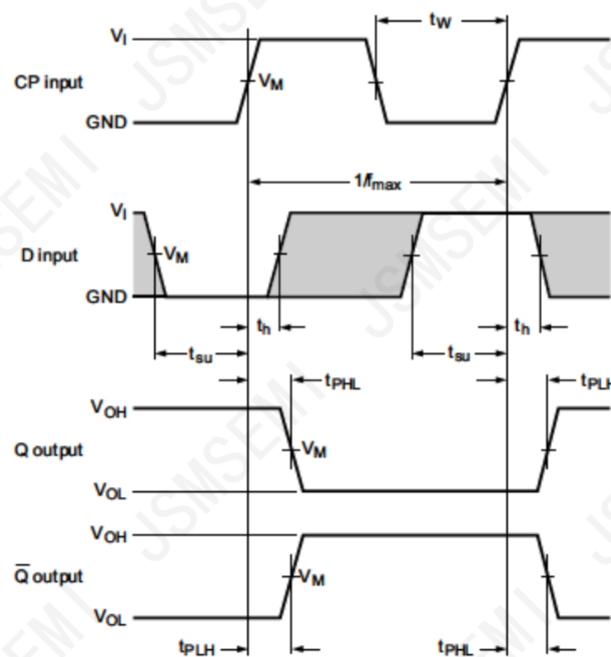


Figure 5. The clock input (CP) to output (Q, $\bar{Q}$) propagation delays, the clock pulse width, the D to CP set-up, the CP to D hold times and the maximum frequency

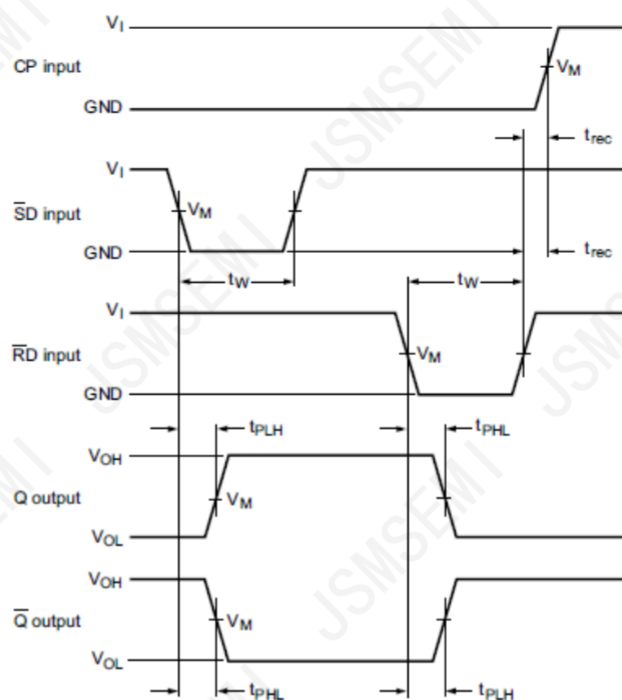


Figure 6. The set ($\bar{S}D$) and reset ($\bar{R}D$) input to output (Q , $\bar{Q}$) propagation delays, the set and reset pulse widths and the $\bar{R}D$ to CP recovery time

4.3、Measurement Points

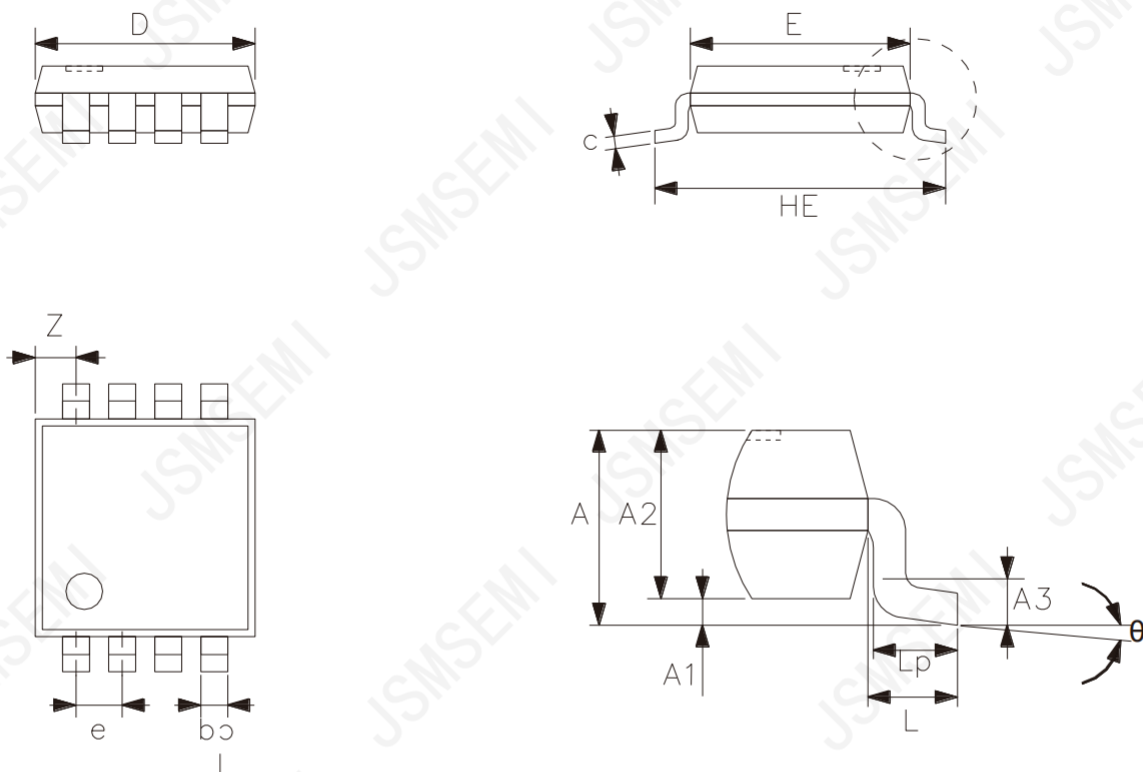
Supply voltage	Input	Output
V_{CC}	V_M	V_M
1.65V to 1.95V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$
2.3V to 2.7V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$
2.7V	1.5V	1.5V
3.0V to 3.6V	1.5V	1.5V
4.5V to 5.5V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$

4.4、Test Data

Supply voltage	Input		Load		V_{EXT}		
V_{CC}	V_I	$t_r = t_f$	C_L	R_L	t_{PLH}, t_{PHL}	t_{PZH}, t_{PHZ}	t_{PZL}, t_{PLZ}
1.65V to 1.95V	V_{CC}	$\leq 3ns$	30pF	1k Ω	open	GND	$2 \times V_{CC}$
2.3V to 2.7V	V_{CC}	$\leq 3ns$	30pF	500 Ω	open	GND	$2 \times V_{CC}$
2.7V	2.7V	$\leq 3ns$	50pF	500 Ω	open	GND	6V
3.0V to 3.6V	2.7V	$\leq 3ns$	50pF	500 Ω	open	GND	6V
4.5V to 5.5V	V_{CC}	$\leq 3ns$	50pF	500 Ω	open	GND	$2 \times V_{CC}$

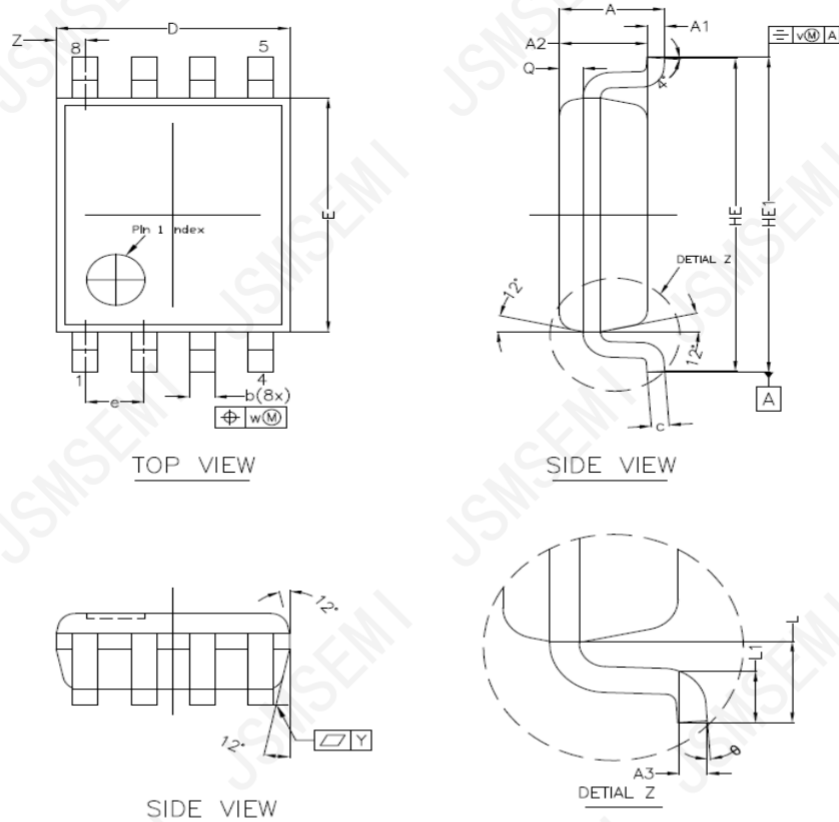
5、Package Information

5.1、TSSOP8



Symbol	Dimensions (mm)	
	Min.	Max.
A	-	1.10
A1	0	0.15
A2	0.75	0.95
A3	0.25	
bp	0.22	0.38
c	0.08	0.18
D	2.90	3.10
E	2.90	3.10
HE	3.90	4.10
L	0.50	
Lp	0.33	0.47
e	0.65	
Z	0.35	0.70
θ	0°	8°

5.2、VSSOP8



Symbol	Dimensions (mm)	
	Min.	Max.
A	-	1.00
A1	0.00	0.15
A2	0.60	0.85
A3	0.12	
Q	0.19	0.21
b	0.17	0.27
c	0.08	0.23
D	1.90	2.10
E	2.20	2.40
HE	3.00	3.20
HE1	3.00	3.40
e	0.50	
L	0.40	
L1	0.15	0.40
Y	0.10	
Z	0.10	0.40
θ	0°	8°

6、Statements And Notes

6.1、The name and content of Hazardous substances or Elements in the product

Part name	Hazardous substances or Elements									
	Lead and lead compounds	Mercury and mercury compounds	Cadmium and cadmium compounds	Hexavalent chromium compounds	Polybrominated biphenyls	Polybrominated biphenyl ethers	Dibutyl phthalate	Butylbenzyl phthalate	Di-2-ethylhexyl phthalate	Diisobutyl phthalate
Lead frame	○	○	○	○	○	○	○	○	○	○
Plastic resin	○	○	○	○	○	○	○	○	○	○
Chip	○	○	○	○	○	○	○	○	○	○
The lead	○	○	○	○	○	○	○	○	○	○
Plastic sheet installed	○	○	○	○	○	○	○	○	○	○
explanation	○: Indicates that the content of hazardous substances or elements in the detection limit of the following the SJ/T11363-2006 standard. ×: Indicates that the content of hazardous substances or elements exceeding the SJ/T11363-2006 Standard limit requirements.									